PROCEEDINGS OF SPIE

Oxide-based Materials and Devices XVI

David J. Rogers Féréchteh H. Teherani Editors

26–29 January 2025 San Francisco, California, United States

Sponsored and Published by SPIE

Volume 13367

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Please use the following format to cite material from these proceedings: Author(s), "Title of Paper," in Oxide-based Materials and Devices XVI, edited by David J. Rogers, Féréchteh H. Teherani, Proc. of SPIE 13367, Seven-digit Article CID Number (DD/MM/YYYY); (DOI URL).

ISSN: 0277-786X

ISSN: 1996-756X (electronic)

ISBN: 9781510684829

ISBN: 9781510684836 (electronic)

Published by

SPIE

P.O. Box 10, Bellingham, Washington 98227-0010 USA Telephone +1 360 676 3290 (Pacific Time)

SPIE.ora

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